









Reference Design



OPA348, OPA2348, OPA4348

SBOS213H-NOVEMBER 2001-REVISED NOVEMBER 2016

OPAx348 1-MHz, 45-µA, CMOS, Rail-to-Rail Operational Amplifiers

1 Features

- Low I_Q: 45 μA (Typical)
- Rail-To-Rail Input and Output
- Single Supply: 2.1 V to 5.5 V
- Input Bias Current: 0.5 pA
- *Micro* Size Packages:
 - 5-Pin SC70
 - 8-Pin SOT-23
 - 14-Pin TSSOP
- Excellent Bandwidth-to-Power Consumption Trade-off
- Number of Channels:
 - OPA348: 1
 - OPA2348: 2
 - OPA4348: 4

2 Applications

- Portable Equipment
- Battery-Powered Equipment
- Smoke Alarms
- CO Detectors
- Medical Instrumentation

3 Description

The OPAx348 series of amplifiers are single-supply, low-power, CMOS operational amplifiers. Featuring an extended bandwidth of 1 MHz, and a supply current of 45 μ A, the OPAx348 series is useful for low-power applications on single supplies of 2.1 V to 5.5 V.

A low supply current of 45 μ A and an input bias current of 0.5 pA, makes the OPAx348 series an optimal candidate for low-power applications such as smoke detectors and other high-impedance sensors.

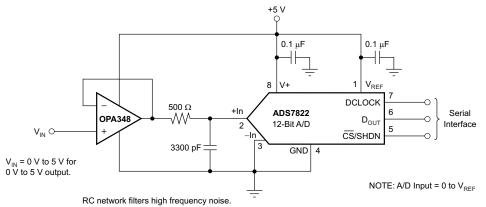
The OPA348 is available in the miniature 5-pin SC70 (SOT), 5-pin SOT-23 (SOT), and 8-pin SO (SOIC) packages. The OPA2348 is available in 8-pin SOT-23 (SOT) and 8-pin SO (SOIC) packages, and the OPA4348 is offered in space-saving 14-pin TSSOP and 14-pin SO (SOIC) packages. The extended temperature range of -40°C to +125°C over all supply voltages offers design flexibility.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	SOIC (8)	4.90 mm × 3.91 mm
OPA348	SOT-23 (5)	2.90 mm × 1.60 mm
	SC70 (5)	2.00 mm × 1.25 mm
	SOIC (8)	4.90 mm × 3.91 mm
OPA2348	SOT-23 (8)	2.90 mm × 1.63 mm
	VSSOP (8)	3.00 mm × 3.00 mm
004249	SOIC (14)	8.65 mm × 3.91 mm
OPA4348	TSSOP (14)	5.00 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.





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4 Revision History

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NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (March 2013) to Revision H

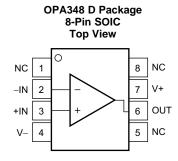
•	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section
•	Changed OPA348 DCK package designator from SOT to SC70 to match Package Option Addendum information
•	Deleted Lead temperature specification from Absolute Maximum Ratings table
•	Reformatted Thermal Information table note
•	Changed second and third paragraphs of Driving A/D Converters section to eliminate redundancy 17
C	hanges from Revision F (October 2012) to Revision G Page
•	Changed 2nd footnote for Absolute Maximum Ratings table
C	hanges from Revision E (September 2012) to Revision F Page

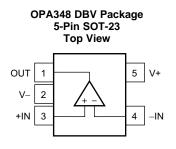


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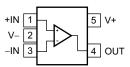


5 Pin Configuration and Functions





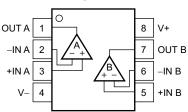
OPA348 DCK Package 5-Pin SC70 (*Micro* size) Top View



Pin Functions: OPA348

	PIN					
NAME	DBV (SOT-23)	DCK (SC70)	D (SOIC)	I/O	DESCRIPTION	
–IN	4	3	2	I	Negative (inverting) input	
+IN	3	1	3	I	Positive (noninverting) input	
NC	_	_	1, 5, 8	_	No internal connection (can be left floating)	
OUT	1	4	6	0	Output	
V–	2	2	4	_	Negative (lowest) power supply	
V+	5	5	7	—	Positive (highest) power supply	

OPA2348 D, DCN, and DGK Packages 8-Pin SOIC, SOT, and VSSOP Top View

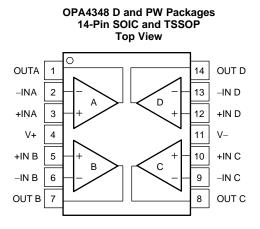


Pin Functions: OPA2348

PIN						
NAME	D (SOIC)	DCN (SOT-23)	DGK (VSSOP)	I/O	DESCRIPTION	
–IN A	2	2	2	Ι	Inverting input, channel A	
–IN B	6	6	6	Ι	Inverting input, channel B	
+IN A	3	3	3	Ι	Noninverting input, channel A	
+IN B	5	5	5	Ι	Noninverting input, channel B	
OUT A	1	1	1	0	Output, channel A	
OUT B	7	7	7	0	Output, channel B	
V–	4	4	4	-	Negative (lowest) power supply	
V+	8	8	8		Positive (highest) power supply	

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Pin Functions: OPA4348

	PIN				
NAME	D (SOIC)	PW (TSSOP)	I/O	DESCRIPTION	
–IN A	2	2	I	Inverting input, channel A	
–IN B	6	6	I	Inverting input, channel B	
–IN C	9	9	I	Inverting input, channel C	
–IN D	13	13	Ι	Inverting input, channel D	
+IN A	3	3	Ι	Noninverting input, channel A	
+IN B	5	5	I	Noninverting input, channel B	
+IN C	10	10	I	Noninverting input, channel C	
+IN D	12	12	I	Noninverting input, channel D	
OUT A	1	1	0	Output, channel A	
OUT B	7	7	0	Output, channel B	
OUT C	8	8	0	Output, channel C	
OUT D	14	14	0	Output, channel D	
V–	11	11	—	Negative (lowest) power supply	
V+	4	4	—	Positive (highest) power supply	

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage	Supply voltage, $V_S = (V+) - (V-)$		7.5	V
	Signal input terminals, voltage ⁽²⁾	(V–) – 0.5	(V+) + 0.5	V
Current	Signal input terminals, current ⁽²⁾		10	mA
Current	Output short-circuit ⁽³⁾	Continuous		
Temperature	Junction, T _J		150	
	Operating, T _A	-65	150	°C
	Storage, T _{stg}	-65	150	

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only. Functional operation of the device at these conditions, or beyond the specified operating conditions, is not implied.

(2) Input terminals are not diode-clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails must be current-limited to 10 mA or less.

(3) Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

			VALUE	UNIT
V	Market and the state of the sta	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Supply voltage	2.1	5.5	V
Specified temperature	-40	125	°C

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6.4 Thermal Information: OPA348

	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	DBV (SOT-23) DCK (SC70) D (SOIC)				
		5 PINS	5 PINS	8 PINS			
R_{\thetaJA}	Junction-to-ambient thermal resistance	229	267	142	°C/W		
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	99	81	90	°C/W		
$R_{\theta JB}$	Junction-to-board thermal resistance	55	55	83	°C/W		
ΨJT	Junction-to-top characterization parameter	7.7	1.2	40	°C/W		
Ψјв	Junction-to-board characterization parameter	54	54	82	°C/W		
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	_	—	—	°C/W		

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics (SPRA953).

6.5 Thermal Information: OPA2348

		OPA2348				
	THERMAL METRIC ⁽¹⁾	D (SOIC)	DGK (VSSOP)	DCN (SOT-23)	UNIT	
		8 PINS	8 PINS	8 PINS		
R_{\thetaJA}	Junction-to-ambient thermal resistance	134	191	147	°C/W	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	90	83	115	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	79	112	32	°C/W	
ΨJT	Junction-to-top characterization parameter	30	18	38	°C/W	
ΨJB	Junction-to-board characterization parameter	78	110	33	°C/W	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	—	—	—	°C/W	

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics (SPRA953).

6.6 Thermal Information: OPA4348

		OPA		
	THERMAL METRIC ⁽¹⁾	D (SOIC)	PW (TSSOP)	UNIT
		14 PINS	14 PINS	
R_{\thetaJA}	Junction-to-ambient thermal resistance	78	121	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	35	49	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	33	63	°C/W
ΨJT	Junction-to-top characterization parameter	7	5.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	33	62	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	—	—	°C/W

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics (SPRA953).

6.7 Electrical Characteristics

at V_S = 2.5 V to 5.5 V, T_A = 25°C, R_L = 100 k Ω connected to V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP MAX	
OFFSET	VOLTAGE				
		$V_{S} = 5 \text{ V}, V_{CM} = (V-) + 0.8 \text{ V}$		1 5	5
V _{OS}	Input offset voltage	$V_{S} = 5 \text{ V}, V_{CM} = (V-) + 0.8 \text{ V},$ at $T_{A} = -40^{\circ}\text{C}$ to 125°C		(mV
dV _{OS} /dT	Input offset voltage drift	At $T_A = -40^{\circ}$ C to 125° C		4	µV/°C
		$V_{\rm S}$ = 2.5 V to 5.5 V, $V_{\rm CM}$ < (V+) $-$ 1.7 V		60 175	5
PSRR	Input offset voltage versus power supply	At $T_A = -40^{\circ}$ C to 125°C, $V_S = 2.5$ V to 5.5 V, $V_{CM} < (V+) - 1.7$ V		300	μV/V
	Channel concretion	At dc		0.2	μV/V
	Channel separation	At f = 1 kHz		134	dB
INPUT VO	DLTAGE RANGE				
V _{CM}	Common-mode voltage range		(V–) – 0.2	(V+) + 0.2	2 V

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Electrical Characteristics (continued)

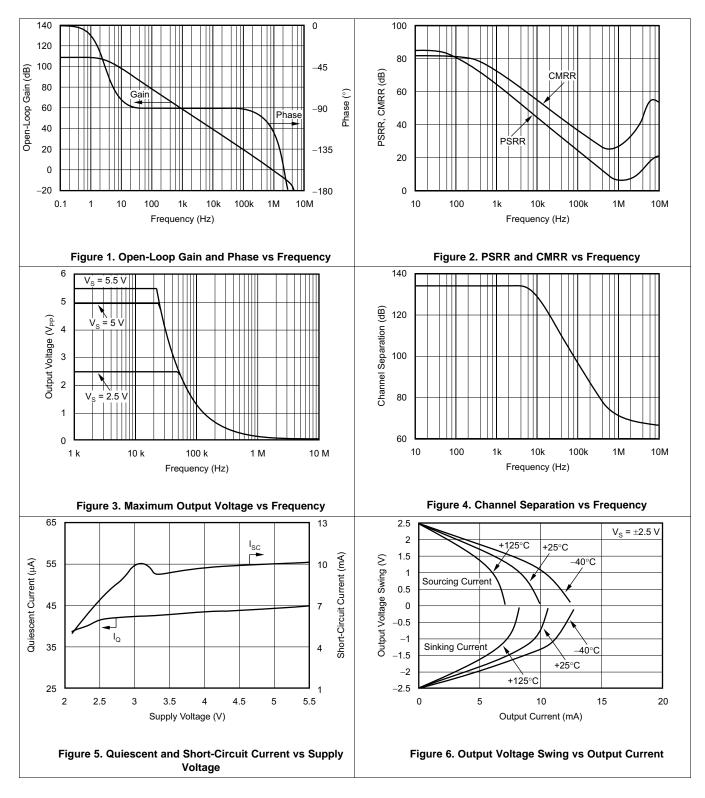
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		$(V-) - 0.2 V < V_{CM} < (V+) - 1.7 V$	70	82		
		$(V-) < V_{CM} < (V+) - 1.7 V,$ at T _A = -40°C to 125°C	66			
CMRR	Common-mode rejection ratio	$V_{\rm S} = 5.5$ V, (V–) – 0.2 V < $V_{\rm CM}$ < (V+) + 0.2 V	60	71		dB
		$V_{S} = 5.5 \text{ V}, (V-) < V_{CM} < (V+),$ at $T_{A} = -40^{\circ}\text{C}$ to 125°C	56			
INPUT B	IAS CURRENT					
I _B	Input bias current			±0.5	±10	pА
l _{os}	Input offset current			±0.5	±10	pА
INPUT IN	MPEDANCE					
	Differential			10 ¹³ 3		Ω∥pF
	Common-mode			10 ¹³ 6		Ω pF
NOISE						
	Input voltage noise	V _{CM} < (V+) - 1.7 V, f = 0.1 Hz to 10 Hz		10		μV _{PP}
e _n	Input voltage noise density	$V_{CM} < (V+) - 1.7 V, f = 1 \text{ kHz}$		35		nV/Hz
i _n	Input current noise density	$V_{CM} < (V+) - 1.7 V, f = 1 \text{ kHz}$		4		fA/Hz
	OOP GAIN	GWI (17)		•		
0. 2.1 2.		$V_{\rm S}$ = 5 V, R _L = 100 kΩ, 0.025 V < V _Ω < 4.975 V	94	108		
٨	Open-loop voltage gain	$V_{\rm S} = 5$ V, R _L = 100 kΩ, 0.025 V < V _O < 4.975 V, at T _A = -40°C to 125°C	90			dB
A _{OL}		$V_{\rm S} = 5$ V, R _L = 5 kΩ, 0.125 V < V _O < 4.875 V	90	98		uв
		$V_{S} = 5$ V, $R_{L} = 5$ kΩ, 0.125 V < V_{O} < 4.875 V, at $T_{A} = -40^{\circ}$ C to 125°C	88			
Ουτρυτ						
		R _L = 100 kΩ, A _{OL} > 94 dB		18	25	
		R_L = 100 kΩ, A_{OL} > 90 dB, at T_A = -40°C to 125°C			25	
	Voltage output swing from rail	$R_{L} = 5 k\Omega, A_{OL} > 90 dB$		100	125	mV
		$R_{L} = 5 \text{ k}\Omega, A_{OL} > 88 \text{ dB},$ at T _A = -40°C to 125°C			125	
I _{SC}	Short-circuit current			±10		mA
CLOAD	Capacitive load drive		See Typic	al Characteristi	cs	
	INCY RESPONSE				Į_	
GBP	Gain-bandwidth product	$C_{I} = 100 \text{ pF}$		1		MHz
SR	Slew rate	$C_L = 100 \text{ pF}, \text{ G} = +1$		0.5		V/µs
	Settling time, 0.1%	$C_L = 100 \text{ pF}, V_S = 5.5 \text{ V}, 2\text{-V Step}, G = +1$		5		
t _S	Settling time, 0.01%	$C_L = 100 \text{ pF}, V_S = 5.5 \text{ V}, 2 \text{ V Step}, G = +1$		7		μs
	Overload recovery time	$C_{L} = 100 \text{ pF}, V_{IN} \times \text{Gain} > V_{S}$		1.6		μs
THD+N	Total harmonic distortion + noise	$C_L = 100 \text{ pF}, V_S = 5.5 \text{ V}, V_O = 3 \text{ V}_{PP},$ G = +1, f = 1 kHz		0.0023%		μο
POWER	SUPPLY	,				
Vs	Specified voltage		2.5		5.5	V
•5	Operating voltage		2.0	2.1	5.5	V
	eportating totago	$I_{O} = 0 \text{ mA}$		45	65	v
l _Q	Quiescent current (per amplifier)	$I_0 = 0$ mA, at $T_A = -40^{\circ}$ C to 125°C		-+0	00	μA

V 25V ----



6.8 Typical Characteristics

at T_A = 25°C, R_L = 100 k\Omega connected to V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)



OPA348, OPA2348, OPA4348

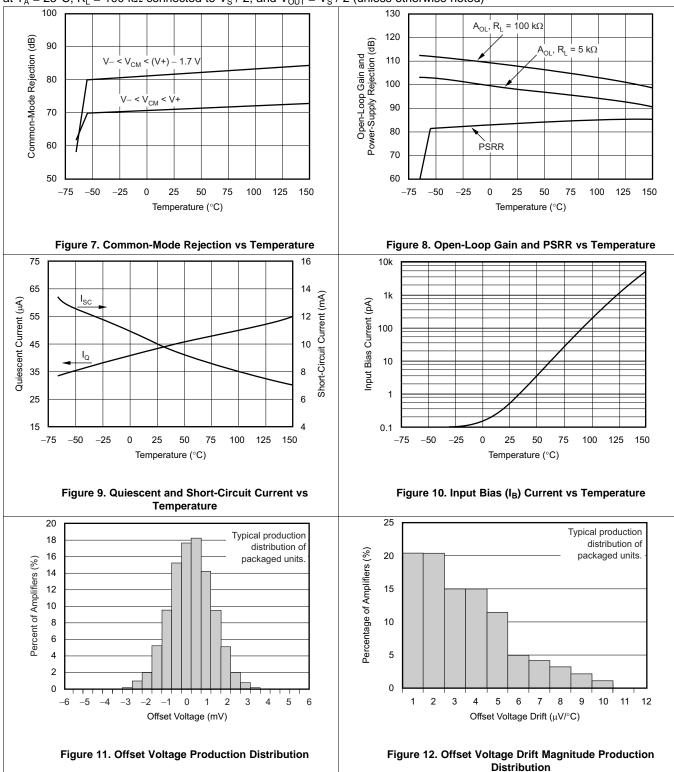
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STRUMENTS

EXAS

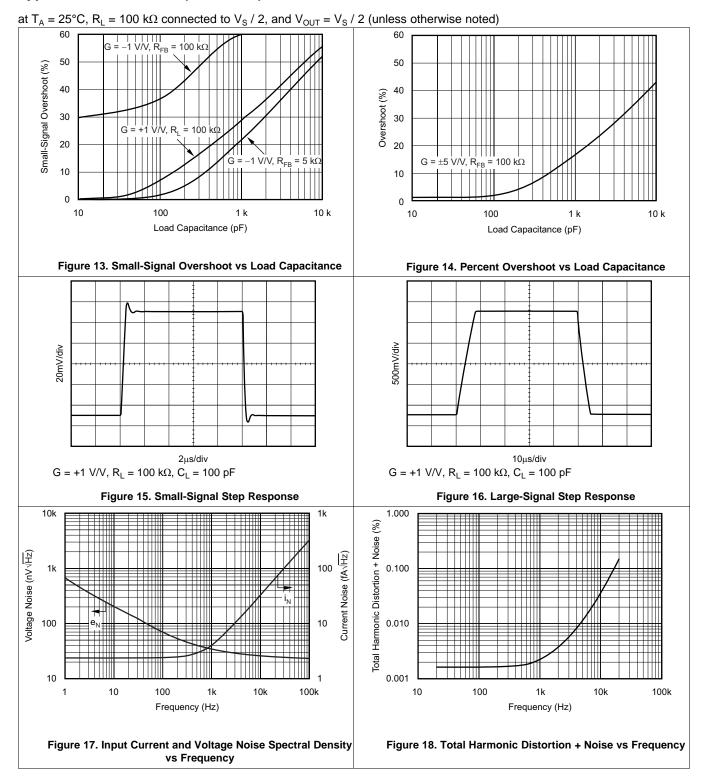
Typical Characteristics (continued)



at $T_A = 25^{\circ}$ C, $R_L = 100 \text{ k}\Omega$ connected to V_S / 2, and $V_{OUT} = V_S$ / 2 (unless otherwise noted)



Typical Characteristics (continued)



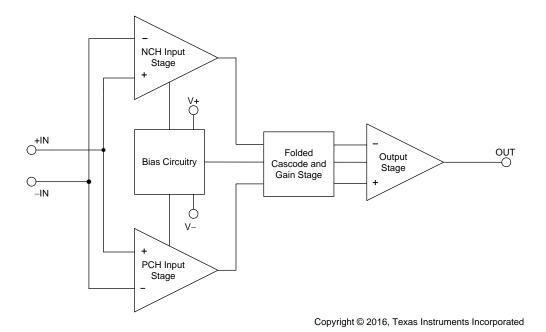
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7 Detailed Description

7.1 Overview

The OPAx348 series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The OPAx348 series features wide bandwidth with rail-to-rail input and output for increased dynamic range.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Operating Voltage

The OPAx348 series op amps are fully specified and tested from 2.5 V to 5.5 V. However, supply voltage may range from 2.1 V to 5.5 V. Parameters are tested over the specified supply range which is an unique feature of the OPAx348 series. All temperature specifications apply from -40° C to $+125^{\circ}$ C. Most behavior remains virtually unchanged throughout the full operating voltage range. Parameters that vary significantly with operating voltages or temperature are shown in the *Typical Characteristics* section.





Feature Description (continued)

7.3.2 Common-Mode Voltage Range

The input common-mode voltage range of the OPA348 series extends 200 mV beyond the supply rails. This extended range is achieved with a complementary input stage which is a N-channel input differential pair in parallel with a P-channel differential pair. The N-channel pair is active for input voltages close to the positive rail, typically (V+) - 1.2 V to 300 mV above the positive supply, while the P-channel pair is on for inputs from 300 mV below the negative supply to approximately (V+) - 1.4 V. There is a small transition region, typically (V+) - 1.4 V to (V+) - 1.2 V, in which both pairs are on. This 200-mV transition region, shown in Figure 19, can vary ±300 mV with process variation. Thus, the transition region (both stages on) ranges from (V+) - 1.7 V to (V+) - 1.5 V on the low end, up to (V+) - 1.1 V to (V+) - 0.9 V on the high end. Within the 200-mV transition region PSRR, CMRR, offset voltage, offset drift, and THD may be degraded compared to operation outside this region.

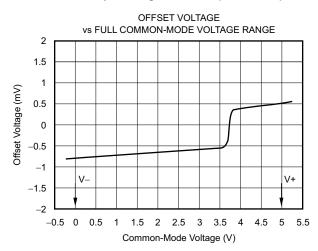


Figure 19. Behavior of Typical Transition Region at Room Temperature

7.3.3 Rail-To-Rail Input

The input common-mode range extends from (V-) - 0.2 V to (V+) + 0.2 V. For normal operation, inputs must be limited to this range. The absolute maximum input voltage is 500 mV beyond the supplies. Inputs greater than the input common-mode range but less than the maximum input voltage, while not valid, do not cause any damage to the op amp. Unlike some other op amps, if input current is limited the inputs may go beyond the power supplies without phase inversion; see Figure 20.

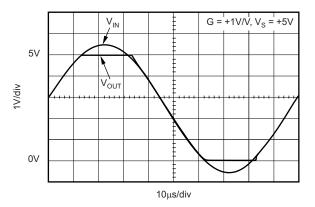
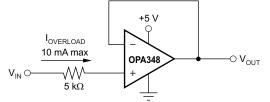


Figure 20. OPA348: No Phase Inversion with Inputs Greater Than The Power-Supply Voltage



Feature Description (continued)

Normally, input currents are 0.5 pA. However, large inputs (greater than 500 mV beyond the supply rails) can cause excessive current to flow in or out of the input pins. Therefore, as well as keeping the input voltage below the maximum rating, it is also important to limit the input current to less than 10 mA. This limiting is easily accomplished with an input voltage resistor, as shown in Figure 21.



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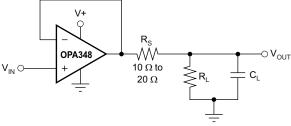
Figure 21. Input Current Protection for Voltages Exceeding the Supply Voltage

7.3.4 Rail-To-Rail Output

A class AB output stage with common-source transistors is used to achieve rail-to-rail output. This output stage is capable of driving 5-k Ω loads connected to any potential between V+ and ground. For light resistive loads (> 100 k Ω), the output voltage can typically swing to within 18 mV from supply rail. With moderately resistive loads (10 k Ω to 50 k Ω), the output voltage can typically swing to within 100 mV of the supply rails while maintaining high open-loop gain (see Figure 6).

7.3.5 Capacitive Load and Stability

The OPA348 in a unity-gain configuration can directly drive up to 250 pF pure capacitive load. Increasing the gain enhances the ability of the amplifier to drive greater capacitive loads (see Figure 13). In unity-gain configurations, capacitive load drive can be improved by inserting a small ($10-\Omega$ to $20-\Omega$) resistor, R_S, in series with the output, as shown in Figure 22. This small resistor significantly reduces ringing while maintaining dc performance for purely capacitive loads. However, if there is a resistive load in parallel with the capacitive load, a voltage divider is created, introducing a direct current (dc) error at the output and slightly reducing the output swing. The error introduced is proportional to the ratio R_S / R_L, and is generally negligible.



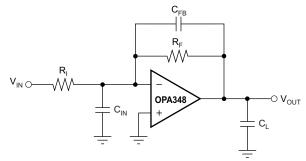
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Figure 22. Series Resistor in Unity-Gain Buffer Configuration Improves Capacitive Load Drive



Feature Description (continued)

In unity-gain inverter configuration, phase margin can be reduced by the reaction between the capacitance at the op amp input, and the gain setting resistors, thus degrading capacitive load drive. Best performance is achieved by using small valued resistors. For example, when driving a 500-pF load, reducing the resistor values from 100 k Ω to 5 k Ω decreases overshoot from 55% to 13% (see Figure 13). However, when large valued resistors cannot be avoided, a small (4-pF to 6-pF) capacitor, C_{FB}, can be inserted in the feedback, as shown in Figure 23. This configuration significantly reduces overshoot by compensating the effect of capacitance, C_{IN}, which includes the amplifier input capacitance and printed circuit board (PCB) parasitic capacitance.



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Figure 23. Improving Capacitive Load Drive

7.4 Device Functional Modes

The OPAx348 has a single functional mode and is operational when the power-supply voltage is greater than 2.1 V (\pm 1.05 V). The maximum power supply voltage for the OPAx348 is 5.5 V (\pm 2.75 V).

ISTRUMENTS

FXAS

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The OPA348 amplifier is a single-supply, CMOS op amp with 1-MHz unity-gain bandwidth and supply current of only 45 μ A. Its performance is optimized for a lower power (2.1 V to 5.5 V), single-supply application, with its input common-mode voltage linear range extending 200 mV beyond the rails and the output voltage swing within 25 mV of either rail.

The OPA348 series features wide bandwidth and unity-gain stability with rail-to-rail input and output for increased dynamic range. Figure 24 shows the input and output waveforms for the OPA348 in unity-gain configuration. Operation is from a single 5-V supply with a 100-k Ω load connected to V_S / 2. The input is a 5-V_{PP} sinusoid. Output voltage is approximately 4.98 V_{PP}.

Power-supply pins must be bypassed with 0.01-µF ceramic capacitors.

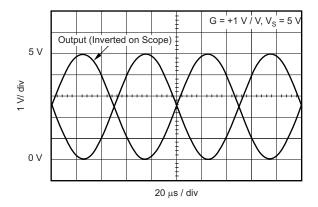


Figure 24. OPA348 Features Rail-to-Rail Input and Output

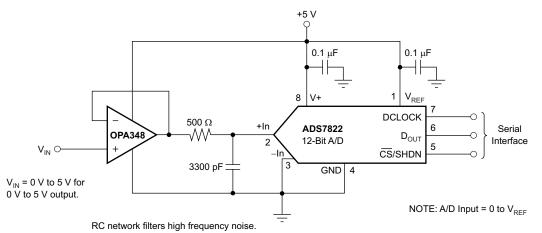


Application Information (continued)

8.1.1 Driving A/D Converters

The OPA348 series op amps are optimized for driving medium-speed sampling analog-to-digital converters (ADCs). The OPA348 op amps buffer the ADC input capacitance and resulting charge injection while providing signal gain.

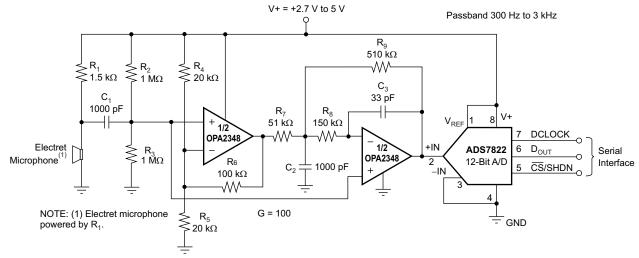
Figure 25 shows the OPA348 in a basic noninverting configuration driving the ADS7822. The ADS7822 is a 12-bit, *micro*POWER sampling converter in the MSOP-8 package. When used with the low-power, miniature packages of the OPA348, the combination is ideal for space-limited, low-power applications. In this configuration, an RC network at the ADC input can be used to provide both an anti-aliasing filter and charge injection current.



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Figure 25. OPA348 in Noninverting Configuration Driving ADS7822

Figure 26 illustrates the OPA2348 driving an ADS7822 in a speech-bandpass filtered data acquisition system. This small, low-cost solution provides the necessary amplification and signal conditioning to interface directly with an electret microphone. This circuit operates with $V_S = 2.7$ V to 5 V with less than 250-µA typical quiescent current.

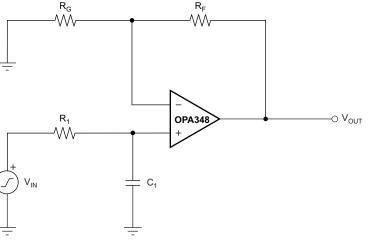


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8.2 Typical Application

Figure 27 shows the OPA348 in a typical noninverting application with input signal bandwidth limited by the input low-pass filter.



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Figure 27. Single-Pole, Low-Pass Filter

Equation 1 and Equation 2 show the relationships for the low-pass cutoff frequency and the low frequency gain and the passive elements surrounding the amplifier.

$$f_{-3 dB} = \frac{1}{2\pi R_1 C_1}$$

$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_1 C_1}\right)$$
(2)

8.2.1 Design Requirements

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to establish this limited bandwidth is to place an RC filter at the noninverting terminal of the amplifier, as shown in Figure 27. If a steeper attenuation level is required, a two-pole or higher-order filter may be used.

8.2.2 Detailed Design Procedure

The design goals for this circuit include these parameters:

- A noninverting gain of 10 V/V (20 dB)
- Design a single-pole response circuit with –3-dB roll-off at 15.9 kHz and 159 Hz
- Modify the design to increase attenuation level to -40-dB/decade (Sallen-Key Filter)

Use these design values:

- $C_1 = 0 \text{ nF}, 10 \text{ nF}, 1 \mu \text{F}$
- $R_1 = 1 k\Omega$
- R_G = 10 kΩ
- R_F = 90 kΩ



Typical Application (continued)

Figure 28 shows how the output voltage of OPA348 changes over frequency depending on the value of C₁ with a constant R₁ of 1 kΩ. Without any filtering of the input signal (C₁ = 0), the -3-dB effective bandwidth is a function of the OPA348 unity-gain bandwidth and closed-loop gain, $f_{(-3dB)} = UGBW/A_{CL}$, where A_{CL} is closed-loop gain and UGBW denotes unity-gain bandwidth. Thus, for a closed-loop gain = 10, $f_{(-3dB)} = 1$ MHz/10 =100 kHz; refer to Figure 28.

To further limit the output bandwidth, an appropriate choice of C₁ must be made: for C₁ = 10 nF, $f_c = \frac{1}{2} = \frac{1}{2}$

$$2\pi \times R_1C_1 = 2\pi \times 1^3 \times 1^{-8} = 15.9 \text{ kHz}.$$

To further limit the bandwidth, a larger C₁ must be used:

choosing C₁ = 1 µF, $f_c = \frac{1}{2\pi \times R_1C_1} = \frac{1}{2\pi \times 1^3 \times 1^{-6}} = 159$ Hz. See Figure 28.

8.2.3 Application Curve

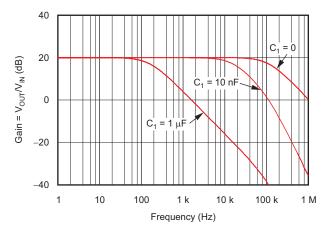
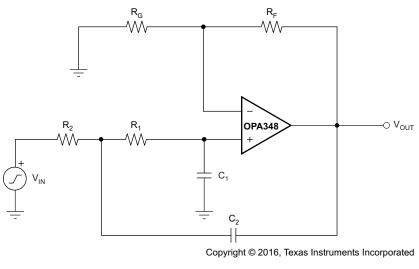


Figure 28. OPA348 Single-Pole AC Gain vs Frequency Response

If even more attenuation is required, a multiple pole filter is required. The Sallen-Key filter may be used for this task, as shown in Figure 29. For best results, the amplifier must have effective bandwidth that is at least 10 times higher than the filter cutoff frequency. Failure to follow this guideline results in a phase shift of the amplifier, which in turn leads to lower precision of the filter bandwidth. Additionally, in order to minimize the loading effect between multiple RC pairs on overall the filter cutoff frequency, choose $R = 10 \times R_1$ and $C_2 = C1/10$; see Figure 29.





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EXAS

Typical Application (continued)

Equation 3, Equation 4, and Equation 5 show the relationships for low-pass cutoff frequency, filter transfer function, and low frequency gain, and the surrounding passive elements.

$$f_{\rm C} = \frac{1}{2\pi\sqrt{R_1C_1R_2C_2}}$$
(3)
$$\frac{V_{\rm OUT(s)}}{V_{\rm IN(s)}} = \frac{G(2\pi f_{\rm c})^2}{s^2 + 2\zeta(2\pi f_{\rm c})s + (2\pi f_{\rm c})^2}$$
(4)

$$G = \frac{R_G + R_F}{R_G}$$
(4)

Use these design values:

- C₁ = 10 nF and C₂ = 1 nF
- $R_1 = 1 \ k\Omega$ and $R_2 = 10 \ k\Omega$
- R_G = 10 kΩ
- R_F = 90 kΩ

Figure 30 shows the Sallen-Key filter second-order response for different RC values: for R and C values above,

$$f_{\rm C} = \frac{1}{2\pi\sqrt{R_1C_1R_2C_2}} = \frac{1}{2\pi\sqrt{1^3 \times 1^{-8} \times 1^4 \times 1^{-9}}} = 15.9 \text{ kHz}.$$

To further limit the bandwidth, a larger RC value must be used: increasing C values 100 times, such as $C_1 = 1 \mu F$ and $C_2 = 0.1 \mu F$, with unchanged resistors, results in the second-order roll-off at $f_c = \frac{1}{2 \pi \sqrt{D - C - D - C}} = \frac{1}{2 \pi \sqrt{D - C - D - C}} = \frac{1}{2 \pi \sqrt{D - C - D - C}}$



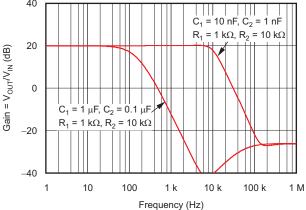


Figure 30. OPA348 Two-Pole, Low-Pass Sallen-Key AC Gain vs Frequency Response



9 Power Supply Recommendations

The OPAx348 is specified for operation from 2.1 V to 5.5 V (\pm 1.05 V to \pm 2.75 V); many specifications apply from -40°C to +125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics*.

CAUTION

Supply voltages larger than 5.5 V can permanently damage the device (see the *Absolute Maximum Ratings* table).

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high impedance power supplies. For more detailed information on bypass capacitor placement, see *Layout*.

10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Connect low equivalent series resistance (ESR), 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
 - Noise can propagate into analog circuitry through the power pins of the circuit as a whole and op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
- Make sure to physically separate digital and analog grounds paying attention to the flow of the ground current. Separate grounding for analog and digital portions of circuitry is one of the simplest and mosteffective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup.
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as
 possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as
 opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As shown in Figure 31, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- Clean the PCB following board assembly for best performance.
- Any precision integrated circuit may experience performance shifts due to moisture ingress into the plastic package. After any aqueous PCB cleaning process, bake the PCB assembly to remove moisture introduced into the device packaging during the cleaning process. A low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.



OPA348, OPA2348, OPA4348

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10.2 Layout Example

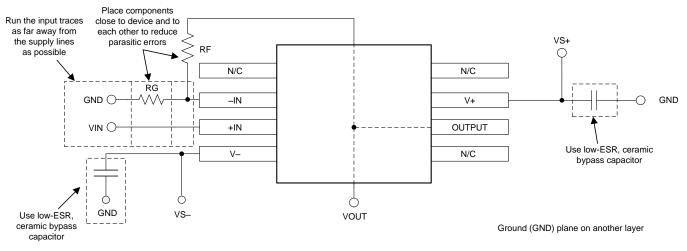


Figure 31. Operational Amplifier Board Layout for Noninverting Configuration



11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

11.1.1.1 TINA-TI[™] (Free Software Download)

TINA[™] is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI[™] is a free, fully-functional version of the TINA software, preloaded with a library of macro models in addition to a range of both passive and active models. TINA-TI provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Analog eLab Design Center, TINA-TI offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

NOTE These files require that either the TINA software (from DesignSoft[™]) or TINA-TI software be installed. Download the free TINA-TI software from the TINA-TI folder.

11.1.1.2 DIP Adapter EVM

The DIP Adapter EVM tool provides an easy, low-cost way to prototype small surface mount devices. The evaluation tool these TI packages: D or U (SOIC-8), PW (TSSOP-8), DGK (MSOP-8), DBV (SOT23-6, SOT23-5 and SOT23-3), DCK (SC70-6 and SC70-5), and DRL (SOT563-6). The DIP Adapter EVM may also be used with terminal strips or may be wired directly to existing circuits.

11.1.1.3 Universal Op Amp EVM

The Universal Op Amp EVM is a series of general-purpose, blank circuit boards that simplify prototyping circuits for a variety of device package types. The evaluation module board design allows many different circuits to be constructed easily and quickly. Five models are offered, with each model intended for a specific package type. PDIP, SOIC, MSOP, TSSOP and SOT-23 packages are all supported.

NOTE

These boards are unpopulated, so users must provide their own devices. TI recommends requesting several op amp device samples when ordering the Universal Op Amp EVM.

11.1.1.4 TI Precision Designs

TI Precision Designs are analog solutions created by TI's precision analog applications experts and offer the theory of operation, component selection, simulation, complete PCB schematic and layout, bill of materials, and measured performance of many useful circuits. TI Precision Designs are available online at http://www.ti.com/ww/en/analog/precision-designs/.

11.1.1.5 WEBENCH[®] Filter Designer

WEBENCH® Filter Designer is a simple, powerful, and easy-to-use active filter design program. The WEBENCH Filter Designer lets you create optimized filter designs using a selection of TI operational amplifiers and passive components from TI's vendor partners.

Available as a web-based tool from the WEBENCH® Design Center, WEBENCH® Filter Designer allows you to design, optimize, and simulate complete multistage active filter solutions within minutes.



11.2 Documentation Support

11.2.1 Related Documentation

The following documents are relevant to using the OPAx348, and recommended for reference. All are available for download at www.ti.com unless otherwise noted.

- Hardware Pace Using Slope Detection (SLAU511).
- Mobile Phone Bank Card Reader Application Report (TIDU399).
- TPS61040 Inverter Design (SLVA008).
- Op Amp Performance Analysis (SBOA054).
- Single-Supply Operation of Operational Amplifiers (SBOA059).
- Tuning in Amplifiers (SBOA067).

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on Alert me to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Related Links

Table 1 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
OPA348	Click here	Click here	Click here	Click here	Click here
OPA2348	Click here	Click here	Click here	Click here	Click here
OPA4348	Click here	Click here	Click here	Click here	Click here

Table 1. Related Links

11.5 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.6 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.7 Trademarks

TINA-TI, E2E are trademarks of Texas Instruments. WEBENCH is a registered trademark of Texas Instruments. TINA, DesignSoft are trademarks of DesignSoft, Inc. All other trademarks are the property of their respective owners.



11.8 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.9 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA2348AID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2348A
OPA2348AID.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2348A
OPA2348AIDCNR	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	B48
OPA2348AIDCNR.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	B48
OPA2348AIDCNRG4	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	B48
OPA2348AIDCNT	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	B48
OPA2348AIDCNT.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	B48
OPA2348AIDCNTG4	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	B48
OPA2348AIDG4	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2348A
OPA2348AIDGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OUTQ
OPA2348AIDGK.B	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OUTQ
OPA2348AIDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU SN NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OUTQ
OPA2348AIDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OUTQ
OPA2348AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2348A
OPA2348AIDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2348A
OPA2348AIDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2348A
OPA348AID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 348A
OPA348AID.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 348A
OPA348AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A48
OPA348AIDBVR.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A48
OPA348AIDBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A48
OPA348AIDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A48



17-Jun-2025

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
OPA348AIDBVT.B	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A48
OPA348AIDBVTG4	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A48
OPA348AIDCKR	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	S48
OPA348AIDCKR.B	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	S48
OPA348AIDCKRG4	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	S48
OPA348AIDCKT	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	S48
OPA348AIDCKT.B	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	S48
OPA348AIDCKTG4	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	S48
OPA348AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 348A
OPA348AIDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 348A
OPA4348AID	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4348A
OPA4348AID.B	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4348A
OPA4348AIDG4	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4348A
OPA4348AIDG4.B	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4348A
OPA4348AIDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4348A
OPA4348AIDR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4348A
OPA4348AIPWR	Active	Production	TSSOP (PW) 14	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 4348A
OPA4348AIPWR.B	Active	Production	TSSOP (PW) 14	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 4348A
OPA4348AIPWRG4	Active	Production	TSSOP (PW) 14	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 4348A
OPA4348AIPWT	Active	Production	TSSOP (PW) 14	250 SMALL T&R	Yes	NIPDAU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 4348A
OPA4348AIPWT.B	Active	Production	TSSOP (PW) 14	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 4348A
OPA4348AIPWTG4	Active	Production	TSSOP (PW) 14	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 4348A

⁽¹⁾ **Status:** For more details on status, see our product life cycle.



PACKAGE OPTION ADDENDUM

17-Jun-2025

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF OPA2348, OPA348, OPA4348 :

• Automotive : OPA2348-Q1, OPA348-Q1, OPA4348-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

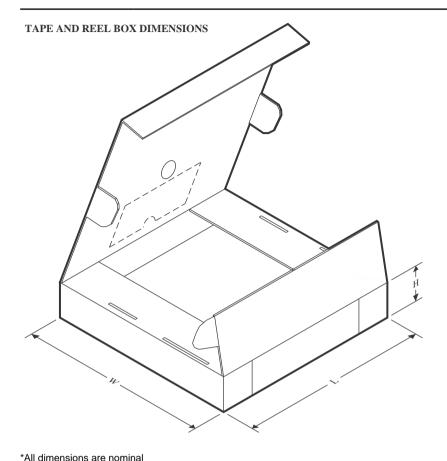


All dimensions are nomina	I											
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2348AIDCNR	SOT-23	DCN	8	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA2348AIDCNT	SOT-23	DCN	8	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA2348AIDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2348AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA348AIDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA348AIDBVT	SOT-23	DBV	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA348AIDBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA348AIDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
OPA348AIDCKT	SC70	DCK	5	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
OPA348AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA4348AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
OPA4348AIPWR	TSSOP	PW	14	2500	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
OPA4348AIPWT	TSSOP	PW	14	250	180.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

24-Jul-2025



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2348AIDCNR	SOT-23	DCN	8	3000	200.0	183.0	25.0
OPA2348AIDCNT	SOT-23	DCN	8	250	200.0	183.0	25.0
OPA2348AIDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
OPA2348AIDR	SOIC	D	8	2500	353.0	353.0	32.0
OPA348AIDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA348AIDBVT	SOT-23	DBV	5	250	195.0	200.0	45.0
OPA348AIDBVT	SOT-23	DBV	5	250	445.0	220.0	345.0
OPA348AIDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
OPA348AIDCKT	SC70	DCK	5	250	200.0	183.0	25.0
OPA348AIDR	SOIC	D	8	2500	353.0	353.0	32.0
OPA4348AIDR	SOIC	D	14	2500	353.0	353.0	32.0
OPA4348AIPWR	TSSOP	PW	14	2500	353.0	353.0	32.0
OPA4348AIPWT	TSSOP	PW	14	250	213.0	191.0	35.0

TEXAS INSTRUMENTS

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24-Jul-2025

TUBE



- B - Alignment groove width

*All dimensions are nominal	

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
OPA2348AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA2348AID.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA2348AIDG4	D	SOIC	8	75	506.6	8	3940	4.32
OPA2348AIDGK	DGK	VSSOP	8	80	330	6.55	500	2.88
OPA2348AIDGK.B	DGK	VSSOP	8	80	330	6.55	500	2.88
OPA348AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA348AID.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA4348AID	D	SOIC	14	50	506.6	8	3940	4.32
OPA4348AID.B	D	SOIC	14	50	506.6	8	3940	4.32
OPA4348AIDG4	D	SOIC	14	50	506.6	8	3940	4.32
OPA4348AIDG4.B	D	SOIC	14	50	506.6	8	3940	4.32

DCK0005A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



DCK0005A

EXAMPLE BOARD LAYOUT

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

Publication IPC-7351 may have alternate designs.
 Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DCK0005A

EXAMPLE STENCIL DESIGN

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

10. Board assembly site may have different recommendations for stencil design.



D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



PW0014A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0014A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0014A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



DBV0005A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DBV0005A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



DGK0008A

EXAMPLE BOARD LAYOUT

[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
- on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



DGK0008A

EXAMPLE STENCIL DESIGN

[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DCN (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Package outline exclusive of metal burr & dambar protrusion/intrusion.
- D. Package outline inclusive of solder plating.
- E. A visual index feature must be located within the Pin 1 index area.
- F. Falls within JEDEC MO-178 Variation BA.
- G. Body dimensions do not include flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.





- NOTES: A. All linear dimensions are in millimeters. B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers D. should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D0014A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



D0014A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0014A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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